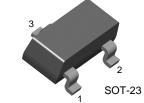


## BCW61A/B/C/D

## **General Purpose Transistor**



#### 1. Base 2. Emitter 3. Collector

## **PNP Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	-32	V
$V_{CEO}$	Collector-Emitter Voltage	-32	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5.0	V
I <sub>C</sub>	Collector Current	-100	mA
P <sub>C</sub>	Collector Power Dissipation	350	mW
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

Refer to KST5086 for graphs

# **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = -2mA$ , $I_B = 0$	-32		
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_{E}$ = -1 $\mu$ A, $I_{C}$ =0	-5		
I <sub>CES</sub>	Collector Cut-off Current	V <sub>CB</sub> = -32V, V <sub>BE</sub> =0		-20	
h <sub>FE</sub>	DC Current Gain				
	: BCW61B	$V_{CE} = -5V, I_{C} = -10\mu A$	20		V
	: BCW61C		40		
	: BCW61D		100		
	: BCW61A	$V_{CE}$ = -5V, $I_{C}$ = -2mA	120	220	V
	: BCW61B		140	310	
	: BCW61C		250	460	
	: BCW61D		380	630	
	: BCW61A	$V_{CE}$ = -5V, $I_{C}$ = -50mA	60		nA
	: BCW61B		80		
	: BCW61C		100		
	: BCW61D		100		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -50mA, I <sub>B</sub> = -1.25mA		-0.55	V
		$I_{C}$ = -10mA, $I_{B}$ = -0.25mA		-0.25	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = -50mA, I <sub>B</sub> = -1.25mA	0.68	1.05	V
		$I_C = -10 \text{mA}, I_B = -0.25 \text{mA}$	0.6	0.85	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE}$ = -5V, $I_{C}$ = -2mA	0.6	0.75	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10V, I <sub>E</sub> =0 f=1MHz		6	pF
NF	Noise Figure	$I_C$ = -0.2mA, $V_{CE}$ = -5V $R_G$ =20K $\Omega$ , f=1KHz		6	dB
t <sub>ON</sub>	Turn On Time	I <sub>C</sub> = -10mA, I <sub>B1</sub> = -1mA		150	ns
t <sub>OFF</sub>	Turn Off Time	$V_{BB}$ = -3.6V, B22= -1mA R1=R2=5.0K $\Omega$ , R <sub>L</sub> =990 $\Omega$		800	ns

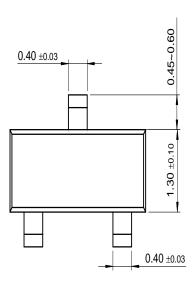
## **Marking Code**

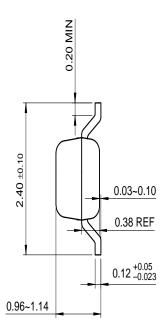
Туре	BCW61A	BCW61B	BCW61C	BCW61D
Mark.	BA	BB	BC	BD

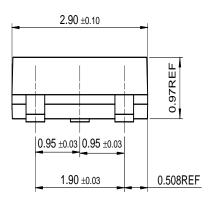


# **Package Demensions**

# **SOT-23**







Dimensions in Millimeters

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